# DDR 1.8 Amp Source / Sink V<sub>TT</sub> Termination Regulator

The NCP51145 is a linear regulator designed to supply a regulated  $V_{TT}$  termination voltage for DDR–II, DDR–III, LPDDR–III and DDR–IV memory applications. The regulator is capable of actively sourcing and sinking  $\pm 1.8$  A peak currents while regulating an output voltage to within  $\pm 20$  mV. The output termination voltage is regulated to track  $V_{DDQ}$  / 2 by two external voltage divider resistors connected to the  $PV_{CC}$ , GND, and  $V_{REF}$  pins.

The NCP51145 incorporates a high–speed differential amplifier to provide ultra–fast response to line and load transients. Other features include source/sink current limiting, soft–start and on–chip thermal shutdown protection.

## **Features**

- For DDR V<sub>TT</sub> Applications, Source/Sink Currents:
- Supports DDR-II to  $\pm 1.8$  A, DDR-III to  $\pm 1.5$  A
- Supports LPDDR-III and DDR-IV to ±1.2 A
- Stable Using Ceramic-Only (Very Low ESR) Capacitors
- Integrated Power MOSFETs
- High Accuracy V<sub>TT</sub> Output at Full–Load
- Fast Transient Response
- Built-in Soft-Start
- Shutdown for Standby or Suspend Mode
- Integrated Thermal and Current-Limit Protection
- V<sub>TT</sub> Remote Sense Available in the DFN8 2x2mm Package
- These Devices are Pb-Free and are RoHS Compliant

## **Typical Applications**

- DDR-II / DR-III / DDR-IV SDRAM Termination Voltage
- Motherboard, Notebook, and VGA Card Memory Termination
- Set Top Box, Digital TV, Printers
- Low Power DDR-3LP



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SOIC-8 EP D SUFFIX CASE 751BU





DFN8 MN SUFFIX CASE 506AA



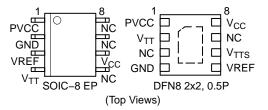
51145 = Specific Device Code XX = Specific Device Code

M = Date CodeA = Assembly Location

Y = Year WW = Work Week ■ = Pb-Free Package

(Note: Microdot may be in either location)

## **PIN CONNECTIONS**



## **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
NCP51145PDR2G	SOIC-8 (Pb-Free)	2500 / Tape & Reel
NCP51145MNTAG	DFN-8 (Pb-Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

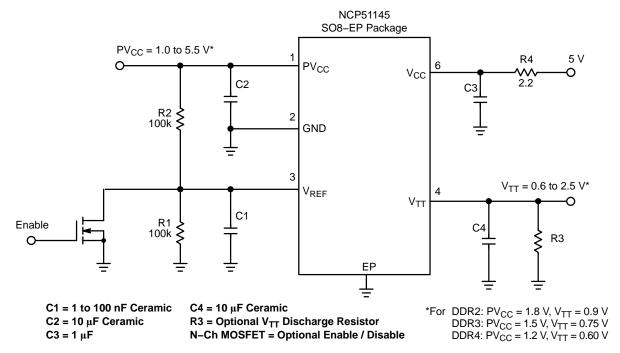


Figure 1. Application Diagram

## PIN FUNCTION DESCRIPTION

Pin No. SO8-EP	Pin No. DFN8	Pin Name	Description
1	1	$PV_{CC}$	Input voltage which supplies current to the output pin. $C_{IN}\cong \frac{1}{2} \bullet C_{OUT}$
2	4	GND	Common Ground
3	5	V <sub>REF</sub>	Buffered reference voltage input equal to $1/2$ of $V_{DDQ}$ and active low shutdown pin. An external resistor divider dividing down the $PV_{CC}$ voltage creates the regulated output voltage. Pulling the pin to ground (0.15 V maximum) turns the device off.
4	2	V <sub>TT</sub>	Regulator output voltage capable of sourcing and sinking current while regulating the output rail. $C_{OUT}$ = 10 $\mu$ F Ceramic, or greater
5, 7, 8	3, 7	NC	True No Connect
6	8	V <sub>CC</sub>	The $V_{CC}$ pin is a 5 V input pin that provides internal bias to the controller. $PV_{CC}$ should always be kept lower or equal to $V_{CC}$ .
-	6	$V_{TTS}$	V <sub>TT</sub> Sense
EP	EP	EPAD	Pad for thermal connection. The exposed pad must be connected to the ground plane using multiple vias for maximum power dissipation performance.

## **ABSOLUTE MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Input Supply Voltage Range ( $V_{CC} \ge PV_{CC}$ ) (Note 1)	PV <sub>CC</sub> , V <sub>CC</sub>	-0.3 to 6	V
Output Voltage Range	V <sub>TT</sub>	-0.3 to 6	V
Reference Input Range	$V_{REF}$	-0.3 to 6	V
Maximum Junction Temperature	T <sub>J(max)</sub>	150	°C
Storage Temperature Range	TSTG	-65 to 150	°C
ESD Capability, Human Body Model (Note 2)	ESDHBM	2	kV
ESD Capability, Machine Model (Note 2)	ESDMM	200	V
Lead Temperature Soldering Reflow (SMD Styles Only), Pb–Free Versions (Note 3)	T <sub>SLD</sub>	260	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- 1. Refer to ELECTRICAL CHĂRACTERISTICS and APPLICATION INFORMATION for Safe Operating Area.
- 2. This device series incorporates ESD protection and is tested by the following methods:
  - ESD Human Body Model tested per AEC-Q100-002 (EIA/JESD22-A114)
  - ESD Machine Model tested per AEC-Q100-003 (EIA/JESD22-A115)
- Latchup Current Maximum Rating: ≤150 mA per JEDEC standard: JÉSD78
- 3. For information, please refer to our Soldering and Mounting Techniques Reference Manual, SOLDERRM/D

## THERMAL CHARACTERISTICS

Rating	Symbol	Value	Unit
Thermal Characteristics, SO8–EP (Note 4) Thermal Resistance, Junction–to–Air (Note 5) Thermal Reference, Junction–to–Lead2 (Note 5)	R <sub>θJA</sub> R <sub>ΨJL</sub>	82 TBD	°C/W

- 4. Refer to ELECTRICAL CHARACTERISTIS and APPLICATION INFORMATION for Safe Operating Area.
- 5. Values based on copper area of 645 mm2 (or 1 in2) of 1 oz copper thickness and FR4 PCB substrate.

## **OPERATING RANGES** (Note 6)

Rating	Symbol	Min	Max	Unit
Input Voltage	PV <sub>CC</sub>	1.0	5.5	V
Bias Supply Voltage	V <sub>CC</sub>	4.75	5.25	V
Ambient Temperature	T <sub>A</sub>	-40	85	°C

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

6. Refer to ELECTRICAL CHARACTERISTICS and APPLICATION INFORMATION for Safe Operating Area.

## **ELECTRICAL CHARACTERISTICS**

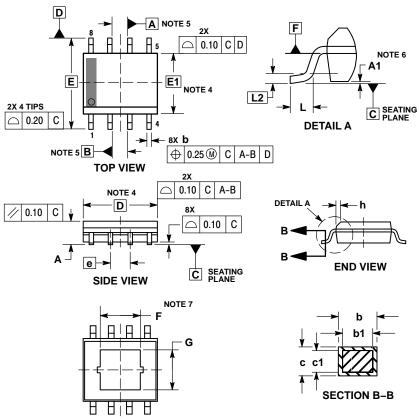
 $PV_{CC} = 1.8 \text{ V} / 1.5 \text{ V}; V_{CC} = 5 \text{ V}; V_{REF} = 0.9 \text{ V} / 0.75 \text{ V}; C_{TT} = 10 \text{ } \mu\text{F} \text{ (Ceramic)}, T_{A} = +25 ^{\circ}\text{C}, unless \text{ otherwise specified}.$ 

Parameter	Test Conditions	Symbol	Min	Тур	Max	Unit
REGULATOR OUTPUT						
Output Offset Voltage	I <sub>out</sub> = 0 A	Vos	-16	-	+16	mV
Load Regulation	$I_{out} = \pm 1.8 \text{ A}, PV_{CC} = 1.8 \text{ V}, V_{REF} = 0.9 \text{ V}$					
	$I_{out} = \pm 1.5 \text{ A}, PV_{CC} = 1.5 \text{ V}, V_{REF} = 0.75 \text{ V}$	D	4			
	$I_{out} = \pm 1.2 \text{ A}, PV_{CC} = 1.35 \text{ V}, V_{REF} = 0.675 \text{ V}$	Reg <sub>load</sub>	-4	_	+4	mV
	$I_{out} = \pm 1.2 \text{ A}, PV_{CC} = 1.2 \text{ V}, V_{REF} = 0.6 \text{ V}$	1				
INPUT AND STANDBY CURREN	TS	•		•		•
Bias Supply Current	I <sub>out</sub> = 0 A	I <sub>BIAS</sub>	_	1	2.5	mA
Standby Current	$V_{REF}$ < 0.2 V (Shutdown), $R_{LOAD}$ = 180 $\Omega$	I <sub>STB</sub>	_	2	90	μΑ
CURRENT LIMIT PROTECTION						
0 11: 7	PV <sub>CC</sub> = 1.8 V, V <sub>REF</sub> = 0.9 V		2	_	3.5	А
Current Limit	PV <sub>CC</sub> = 1.5 V, V <sub>REF</sub> = 0.75 V	I <sub>LIM</sub>	1.5	_	3.5	
SHUTDOWN THRESHOLDS		•		•		•
01 11 71 1 11111	Enable	$V_{IH}$	V <sub>IH</sub> 0.45 -		_	
Shutdown Threshold Voltage	Shutdown	V <sub>IL</sub> – – 0.		0.15	V	
THERMAL SHUTDOWN		-	-	-	-	
Thermal Shutdown Temperature	V <sub>CC</sub> = 5 V	T <sub>SD</sub>	-	125	_	°C
Thermal Shutdown Hysteresis	V <sub>CC</sub> = 5 V	T <sub>SH</sub>	_	35	-	°C

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

## PACKAGE DIMENSIONS

## SOIC8-NB EP CASE 751BU ISSUE E



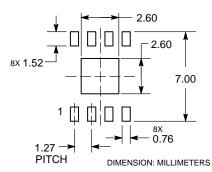
**BOTTOM VIEW** 

## NOTES:

- DIMENSIONING AND TOLERANCING PER ASME
- Y14.5M, 1994. CONTROLLING DIMENSION: MILLIMETERS.
- DIMENSION & DOES NOT INCLUDE DAMBAR
  PROTRUSION. ALLOWABLE PROTRUSION SHALL
  BE 0.10mm IN EXCESS OF MAXIMUM MATERIAL
  CONDITION. 3.
- CONDITION.
  DIMENSION D DOES NOT INCLUDE MOLD FLASH,
  PROTRUSIONS, OR GATE BURRS. MOLD FLASH,
  PROTRUSIONS, OR GATE BURRS SHALL NOT
  EXCEED 0.15mm PER SIDE. DIMENSION E DOES
  NOT INCLUDE INTERLEAD FLASH OR
  PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25mm PER SIDE. DIMENSIONS D AND E ARE DETERMINED AT
- 5. DIMENSIONS A AND B ARE TO BE DETERMINED
- DIMENSIONS A AND B ARE TO BE DETERMINED AT DATUM F.
  AT DATUM F.
  AT IS DEFINED AS THE VERTICAL DISTANCE FROM THE SEATING PLANE TO THE LOWEST POINT ON THE PACKAGE BODY.
  TAB CONTOUR MAY VARY MINIMALLY TO INCLUDE
- TOOLING FEATURES.

	MILLIMETERS			
DIM	MIN	MAX		
Α	1.35	1.75		
A1	0.00	0.10		
b	0.31	0.51		
b1	0.28	0.48		
С	0.17	0.25		
с1	0.17	0.23		
D	4.90 BSC			
Е	6.00 BSC			
E1	3.90 BSC			
е	1.27	1.27 BSC		
F	1.55	2.39		
G	1.55	2.39		
h	0.25	0.50		
Ĺ	0.40	1.27		
L2	0.25 BSC			

## **RECOMMENDED SOLDERING FOOTPRINT\***



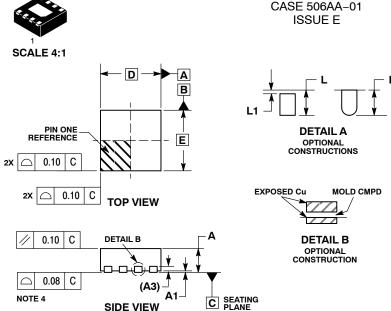
\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

DETAIL A

е

- D2 →

**BOTTOM VIEW** 



0.10 C

Ф

AB

0.05 C NOTE 3



**DATE 22 JAN 2010** 

#### NOTES

- DIMENSIONING AND TOLERANCING PER
- ASME Y14.5M, 1994 . CONTROLLING DIMENSION: MILLIMETERS.
- DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN
- 0.15 AND 0.20 MM FROM TERMINAL TIP. COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS.

	MILLIMETERS			
DIM	MIN	MAX		
Α	0.80	1.00		
A1	0.00	0.05		
А3	0.20	REF		
b	0.20 0.30			
D	2.00 BSC			
D2	1.10 1.30			
E	2.00 BSC			
E2	0.70	0.90		
е	0.50 BSC			
K	0.30 REF			
L	0.25	0.35		
L1		0.10		

## **GENERIC MARKING DIAGRAM\***



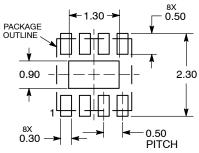
XX = Specific Device Code

= Date Code = Pb-Free Device

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■",

## **RECOMMENDED SOLDERING FOOTPRINT\***

may or may not be present.



**DIMENSIONS: MILLIMETERS** 

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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DESCRIPTION:	DFN8, 2.0X2.0, 0.5MM PITCH		PAGE 1 OF 1	

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